

SEMITOP[®] 3

IGBT Module

SK15GD12T4ET

Features

- One screw mounting module
- Trench4 IGBT technology
- CAL4 technology FWD
- Integrated NTC temperature sensor

Typical Applications*

Remarks

• V_{CE,sat} , V_F = chip level value

 $T_s = 25 \text{ °C}$, unless otherwise specified **Absolute Maximum Ratings** Symbol |Conditions Values Units IGBT 1200 V_{CES} T_i = 25 °C V T_i = 175 °C T_s = 25 °C 27 А I_{C} T_s = 70 °C 21 А 45 А I_{CRM} = 3 x I_{Cnom} I_{CRM} ± 20 V V_{GES} V_{CC} = 800 V; $V_{GE} \le 15$ V; T_{i} = 150 °C 10 μs t_{psc} VCES < 1200 V Inverse Diode T_i = 175 °C T_s = 25 °C 21 А I_{F} T_s = 70 °C 17 А 45 А I_{FRM} = 3 x I_{Fnom} I_{FRM} I_{FSM} $t_n = 10 \text{ ms}$; half sine wave $T_i = 150 \text{ °C}$ 90 А Module А I_{t(RMS)} °C Τ_{vj} -40 ... +175 -40 ... +125 °C T_{stg} V_{isol} AC, 1 min. 2500 V

Characteristics T _s =			25 °C, unless otherwise specified			
Symbol	Conditions		min.	typ.	max.	Units
IGBT						
V _{GE(th)}	V_{GE} = V_{CE} , I_C = 0,5 mA		5	5,8	6,5	V
I _{CES}	V_{GE} = 0 V, V_{CE} = V_{CES}	T _j = 25 °C			1,0	mA
		T _j = 150 °C				mA
I _{GES}	V _{CE} = 0 V, V _{GE} = 20 V	T _j = 25 °C			120	nA
		T _j = 150 °C				nA
V _{CE0}		T _j = 25 °C		0,8	0,9	V
		T _j = 150 °C		0,7	0,8	V
r _{CE}	V _{GE} = 15 V	T _j = 25°C		70	77	mΩ
		T _j = 150°C		100	110	mΩ
V _{CE(sat)}	I _{Cnom} = 15 A, V _{GE} = 15 V	T _j = 25°C _{chiplev.}		1,85	2,05	V
		T _j = 150°C _{chiplev.}		2,25	2,45	V
C _{ies}				0,9		nF
C _{oes}	V_{CE} = 25, V_{GE} = 0 V	f = 1 MHz		0,08		nF
C _{res}				0,055		nF
Q_G	V _{GE} =-7V+15V			65		nC
t _{d(on)}				16		ns
t _r	R_{Gon} = 16 Ω	V _{CC} = 600V		14		ns
E _{on}	di/dt = 2750 A/µs	I _C = 15A		0,83		mJ
t _{d(off)}	$R_{Goff} = 16 \Omega$	$T_{j} = 150 \text{ °C}$		273		ns
t _f E _{off}	di/dt = 2750 A/µs	V _{GE} = -7+15 V		85 1,52		ns mJ
R _{th(j-s)}	per IGBT			1,65		K/W



GD-ET



Characteristics

Inverse Diode

Symbol |Conditions

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IIIVEI SE I	Dioue				
$V_F = V_{EC}$	I _{Fnom} = 15 A; V _{GE} = 0 V	T _j = 25 °C _{chiplev.}	2,	38 2,71	V
		T _j = 150 °C _{chiplev} .	2,	44 2,77	V
V _{F0}		T _j = 25 °C	1	,3 1,5	V
		T _j = 150 °C	0	,9 1,1	V
r _F		T _j = 25 °C	7	2 80,6	mΩ
		T _j = 150 °C	10	2,7 111,3	mΩ
I _{RRM}	I _F = 15 A	T _i = 150 °C	2	8	A
Q _{rr}	di/dt = 2750 A/µs		0	,3	μC
E _{rr}	V _{CC} = 600V		0,	82	mJ
R _{th(j-s)D}	per diode		2,	34	K/W
M _s	to heat sink		2,25	2,5	Nm
w			3	0	g
Tempera	ature sensor				
R ₁₀₀	T _s =100°C (R ₂₅ =5kΩ)		493	±5%	Ω

min.

typ.

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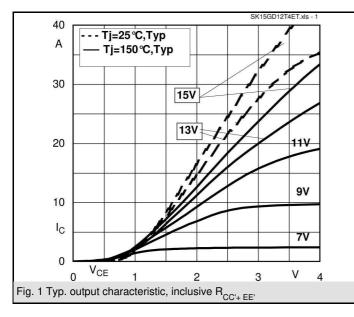
Remarks

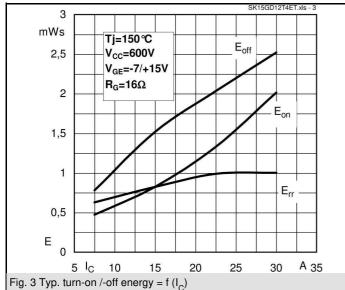
• V_{CE,sat} , V_F = chip level value

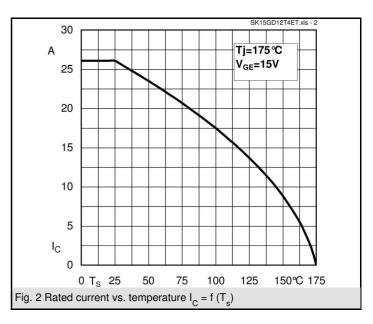


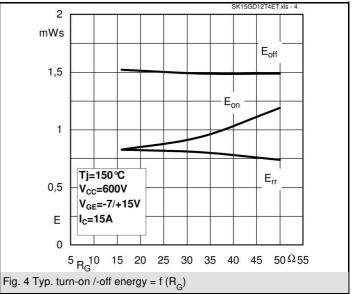
GD-ET

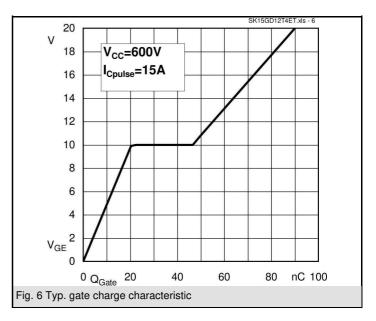
max. Units

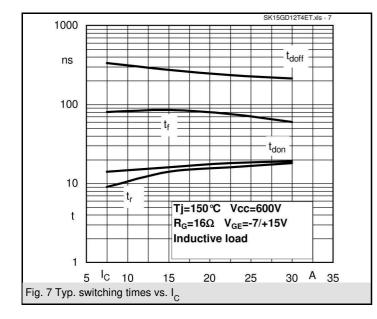


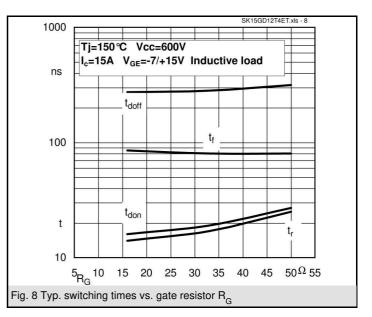


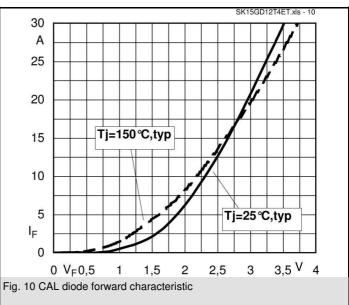


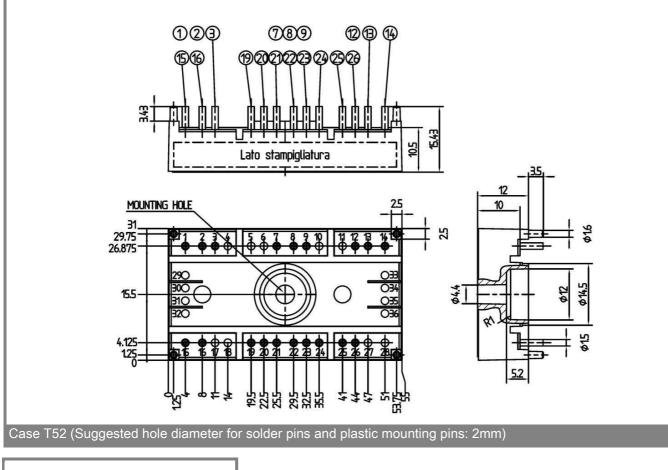


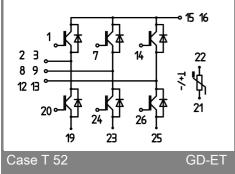












This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

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